

Data sheet acquired from Harris Semiconductor SCHS098D – Revised October 2003

CD40107B Types

CMOS Dual 2-Input NAND Buffer/Driver

High-Voltage Type (20-Volt Rating)

The CD40107B is a dual 2-input NAND buffer/driver containing two independent 2-input NAND buffers with open-drain single n-channel transistor outputs. This device features a wired-OR capability and high output sink current capability (136 mA typ. at $V_{DD}=10~V,~V_{DS}=1~V$). The CD40107B is supplied in 8-lead hermettic dual-in-line ceramic packages (F3A suffix), 8-lead dual-in-line plastic packages (E suffix), 8-lead small-outline packages (M, M96, MT, and PSR suffixes), and 8-lead thin shrink small-outline packages (PW and PWR suffixes).

Features:

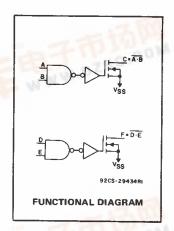
- 32 times standard B-Series output current drive sinking capability — 136 mA typ.
 VDD = 10 V, VDS = 1 V
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range;
 100 nA at 18 V and 25°C
- 5-V, 10-V, and 15-V parametric ratings
- Noise margin, full package temperature range, R_L to V_{DD} = 10 kΩ:

1 V at V_{DD} = 5 V

2 V at V_{DD} = 10 V

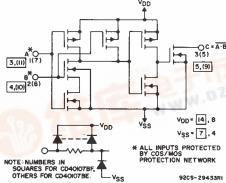
2.5 V at V_{DD} = 15 V

Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



Applications

- Driving relays, lamps, LEDs
- Line driver
- Level shifter (up or down)



TRUTH TABLE A B C 0 0 1* 2* 1 0 1* 2* 0 1 1* 2* 1 1 0 0 1 1* 2*

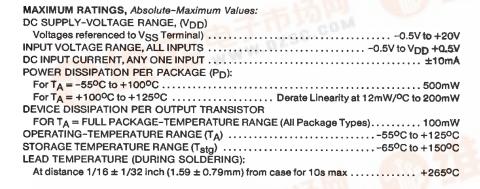
*Requires external pull-up resistor (R_L) to V_{DD}.

#Without pull-up resistor (3-state).

Fig. 1 — Schematic diagram of CD40107B (one of 2 gates)

AMBIENT TEMPERATURE (TA) 25 °C GREO GATE-TO-SOURCE VOLTAGE (VGS) 15 V GREO GATE-TO-SOURCE VOLTAGE (VGS) 15 V DE ANO GREO GATE-TO-SOURCE VOLTAGE (VGS) 15 V

Fig.2 — Typical output low (sink) current characteristics.



RECOMMENDED OPERATING CONDITIONS

df.dzsc.com

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIF		
CHARACTERISTIC	MIN.	MAX.	UNITS
Supply-Voltage Range (For TA=	3	18	v

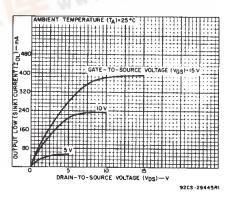


Fig.3 – Minimum output low (sink) current characteristics.

CD40107B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}$ C, $C_L = 50$ pF, input $t_r, t_f = 20$ ns

	TEST CONDIT	LIMITS			
CHARACTERISTIC		V _{DD} Volts	Typ.	Max.	UNITS
Propagation Delay:		5	100	200	
High-to-Low, tpHL	$R_L^* = 120 \Omega$	10	45	90	ns
- THE	1	15	30	60	
Low-to-High, tPLH		5	100	200	ns
	R _L * = 120 Ω	10	60	120	
		15	50	100	
Transition Time:		5	50	100	ns
High-to-Low, tTHL	RL* = 120 Ω	10	20	40	
		15	10	20	
		5	50 .	100	
Low-to-High, t _{TLH}	RL* = 120 Ω	10	35	70	ns
		15	25	50	1
Average Input Capacitance, CIN	Any Input		5	7.5	pF
Average Output Capacitance, COUT	Any Output		30	-	pF

^{*} RL is external pull-up resistor to VDD.

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
13110	Vo	VIN	VIN VDD					+25			
	(V)	(V)	(V)	-55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent Device	-	0,5	5	1	1	30	30	_	0.02	1	
Current		0,10	10	2	2	60	60	-	0.02	2	
IDD Max.	_	0,15	15	4	4	120	120	_	0.02	4	μΑ
-00	_	0,20	20	20	20	600	600	-	0.04	20	
Output Low	0.4	0,5	5	21	20	14	12	16	32	_	mA
(Sink) Current	1	0,5	5	44	42	30	25	34	68	_	
IOL Min.	0.5	0,10	10	49	46	32	28	37	74	_	
.OL	1	0,10	10	89	85	60	51	68	136		
	0.5	0,15	15	66	63	44	38	50	100	-	
Output High (Source) Current IOH Min.	No Internal Pull-Up Device										
Input Low	4.5	1	5	1.5				_	1.5		
Voltage	9	-	10			3		_	-	3	
VIL Max.*	13.5	_	15		4			_	_	4	V
Input High Voltage	0.5,4.5	1	5		3.5			3.5	_	_	V
	1,9	-	10			7		7		_	
VIH Min.*	1.5,13.5		15		11				_	_	
Input Current IN Max.		0,18	18	±0.1	±0.1	±1	±1	_	±10 ⁻⁵	±0.1	μΑ
Output Leakage Current IOZ Max.	18	0,18	18	2	2	20	20	-	10-4	2	μΑ

^{*} Measured with external pull-up resistor, RL = 10 k Ω to VDD.

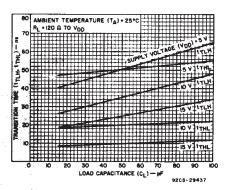


Fig.4 — Typical transition time as a function of load capacitance.

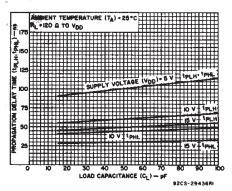


Fig.5 — Typical propagation delay time as a function of load capacitance.

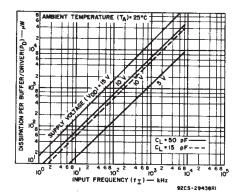


Fig.6 - Typical power dissipation as a function of input frequency.

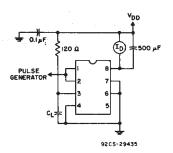
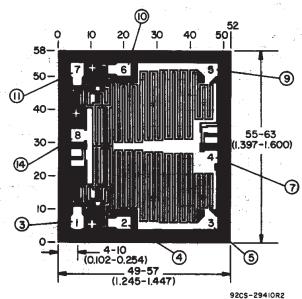


Fig. 7 – Power-dissipation test circuit for CD40107BE.

CD40107B Types



NOTE: NOS. IN PADS FOR CD40107BE NOS. OUTSIDE CHIP FOR CD40107BF

Dimensions and Pad Layout for CD40107BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).



TERMINAL ASSIGNMENTS

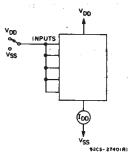


Fig.8 - Quiescent-device current test circuit,

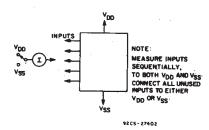


Fig. 9 - Input-current test circuit.

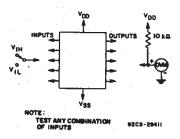


Fig. 10 — Input-voltage test circuit.

Special Considerations for CD40107B

1. Limiting Capacitive Currents for CL > 500 pF, VDD > 15 V.

For VDD > 15 V, and load capacitance (CL) from output to ground > 500 pF, an external 25 Ω series limiting resistor should be inserted between the output terminal and CL. No external resistor is necessary if CL < 500 pF or VDD < 15 V.

2. Driving Inductive Loads

When using the CD40107B to drive inductive loads, the load should be shunted with a diode to prevent high voltages from developing across the CD40107B output.



PACKAGE OPTION ADDENDUM

28-Feb-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
CD40107BE	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD40107BF	ACTIVE	CDIP	J	14	1	None	Call TI	Level-NC-NC-NC
CD40107BF3A	ACTIVE	CDIP	J	14	1	None	Call TI	Level-NC-NC-NC
CD40107BM	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BM96	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BMT	ACTIVE	SOIC	D	8	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BPSR	ACTIVE	SO	PS	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD40107BPW	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
CD40107BPWR	ACTIVE	TSSOP	PW	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

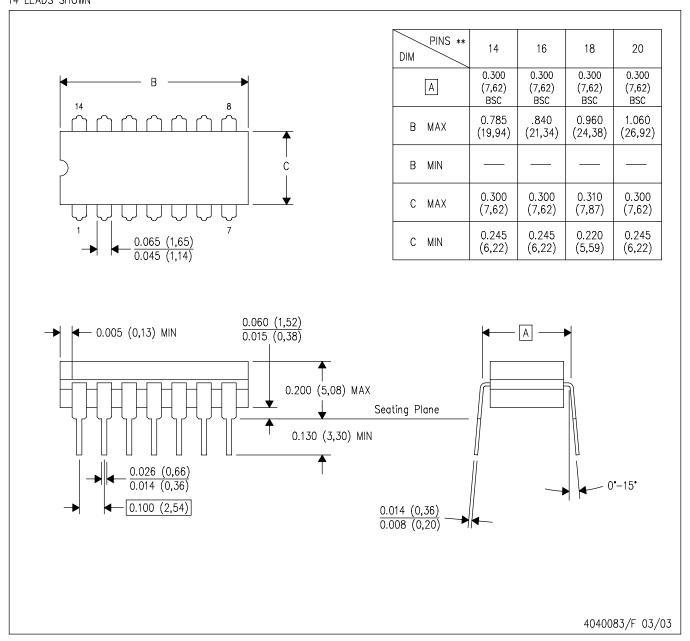
Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

14 LEADS SHOWN

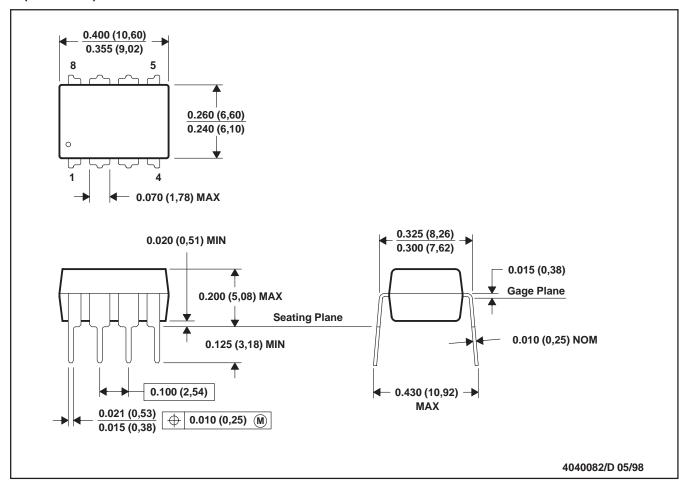


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



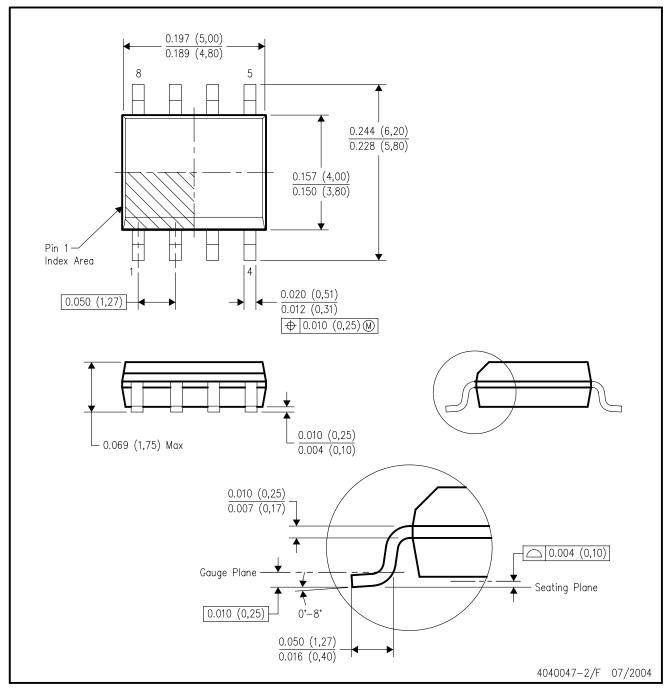
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001



D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

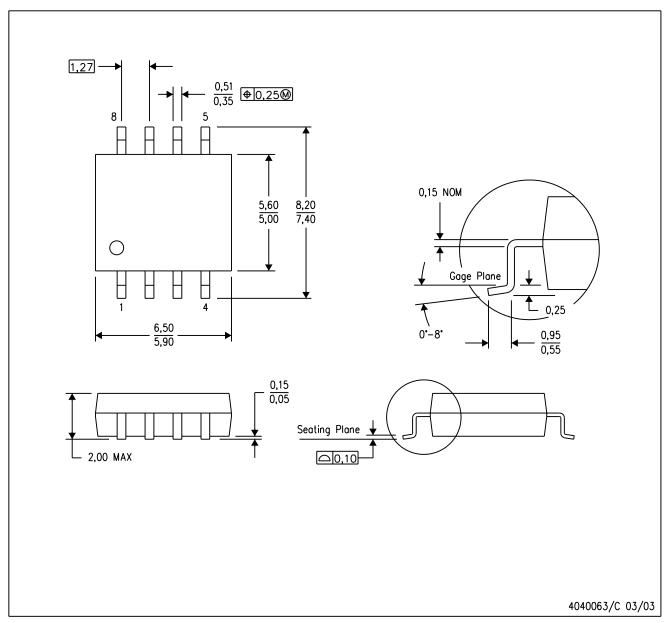
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AA.



MECHANICAL DATA

PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
		Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265